

25 MIPS, 16 kB Flash, 10-Bit ADC, 20-pin Mixed-Signal MCU

Analog Peripherals

10-Bit ADC

- Programmable throughput up to 200 ksps
- Up to 16 external inputs; programmable as single-ended or differential
- Reference from internal V_{RFF}, V_{DD}, or external pin
- Internal or external start of conversion sources
- Built-in temperature sensor

10-bit DAC (Current Mode)

Comparator

- Programmable hysteresis and response time
- Configurable to generate interrupts or reset
- Low current

On-Chip Debug

- On-chip debug circuitry facilitates full speed, non-intrusive in-system debug (no emulator required)
- Provides breakpoints, single stepping, watchpoints
- Inspect/modify memory, registers, and stack
- Superior performance to emulation systems using ICE-chips, target pods, and sockets

Supply Voltage: 2.7 to 3.6 V

Temperature Range: -40 to +85 °C

High-Speed 8051 µC Core

- Pipelined instruction architecture; executes 70% of instructions in 1 or 2 system clocks
- Up to 25 MIPS throughput with 25 MHz clock
- Expanded interrupt handler

Memory

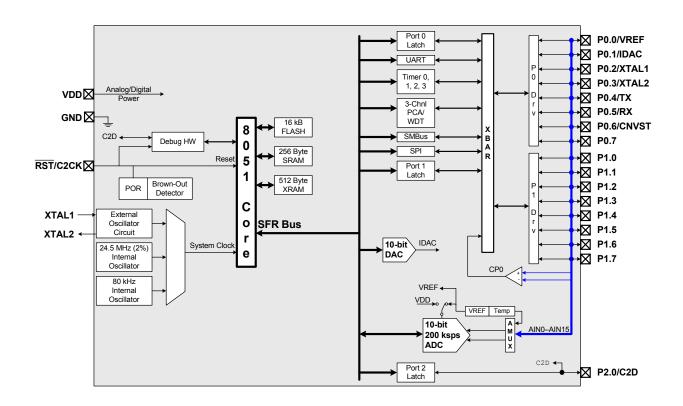
- 768 bytes data RAM
- 16 kB Flash; in-system programmable in 512 byte sectors (512 bytes are reserved)

Digital Peripherals

- Up to 21 port I/O: all are 5 V tolerant
- Hardware SMBus™ (I²C™ compatible), SPI™, and crystaless-UART serial ports available concurrently
- Programmable 16-bit counter/timer array with three capture/compare modules, WDT
- 4 general-purpose 16-bit counter/timers
- Timer with real-time clock mode
- Clock sources
- Two internal oscillators:
 - Precision 24.5 MHz, 2% accuracy over V_{DD} and temperature
 - 80 kHz low frequency, low-power
- External oscillator: Crystal, RC, C, or Clock (1 or 2 pin modes)
- Can switch between clock sources on-the-fly
- Suspend mode for maximum power savings with fast wake-up (<1 us)

Package

- 20-pin QFN
- Pin compatible with C8051F33x family of devices





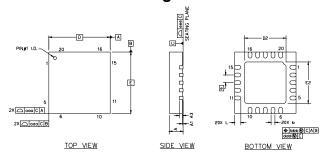
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Selected Electrical Specifications

 $(T_A = -40 \text{ to } +85 \text{ C}^{\circ}, V_{DD} = 2.7 \text{ V} \text{ unless otherwise specified})$

Parameter	Conditions	Min	Тур	Max	Units	
Global Characteristics			•		•	
Supply Voltage			_	3.6	V	
Supply Current with CPU Active	Clock = 25 MHz	_	TBD	_	mA	
,	Clock = 1 MHz	_	TBD	_	mA	
	Clock = 80 kHz; V _{DD} monitor disabled	_	TBD	_	μΑ	
	Clock = 32 kHz; V _{DD} monitor disabled	_	TBD	_	μA	
Supply Current (shutdown)	Oscillator off; V _{DD} monitor disabled	— TBD —			μA	
Clock Frequency Range		_ 25				
Internal Oscillators						
Frequency (OSC0)			24.5	25.0	MHz	
Frequency (OSC1)			80	_	kHz	
A/D Converter			•		•	
Resolution					bits	
Integral Nonlinearity			±1/2	TBD	LSB	
Differential Nonlinearity	Guaranteed monotonic	<u> </u>	±1/2	TBD	LSB	
Signal-to-Noise Plus Distortion			55.5	_	dB	
Throughput Rate			_	200	ksps	
Input Voltage Range			_	V_{REF}	V	
D/A Converter		•	*		•	
Resolution					bits	
Integral Nonlinearity			±1/2	_	LSB	
Differential Nonlinearity	Guaranteed monotonic	_	±1/2	TBD	LSB	
Output Settling Time			5	_	μs	
Comparator	-	1.0	1			
Response Time Mode0	(CP+) – (CP–) = 100 mV	_	TBD	_	μs	
Current Consumption Mode0			TBD	_	μA	
Response Time Mode1	(CP+) - (CP-) = 100 mV	_	TBD	_	μs	
Current Consumption Mode1			TBD	_	μA	
Response Time Mode2	(CP+) - (CP-) = 100 mV	_	TBD	_	μs	
Current Consumption Mode2			TBD	_	μA	
Response Time Mode3	(CP+) – (CP–) = 100 mV	_	TBD		μs	
Current Consumption Mode3			TBD	_	μA	

QFN-20 Package Information



Dimension	Millimeters			Dimension	Millimeters		
	Min	Nom	Max		Min	Nom	Max
Α	0.80	0.90	1.00	E	4.00 BSC.		
A1	0.03	0.07	0.11	E2	2.55	2.70	2.85
A3	0.25 REF			L	0.30	0.40	0.50
b	0.18	0.25	0.30	aaa	_	_	0.15
D	4.00 BSC.			bbb	_	_	0.10
D2	2.55	2.70	2.85	ddd	_	_	0.05
е	0.50 BSC.			eee	_	_	0.08

C8051F336DK Development Kit



Small Form Factor